

isc Silicon NPN Power Transistor

2SC4336

DESCRIPTION

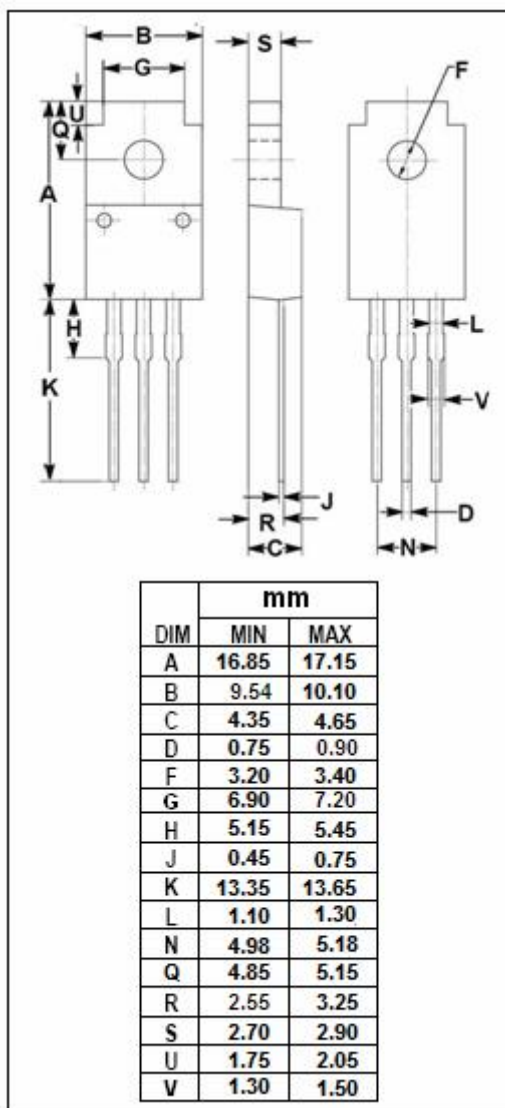
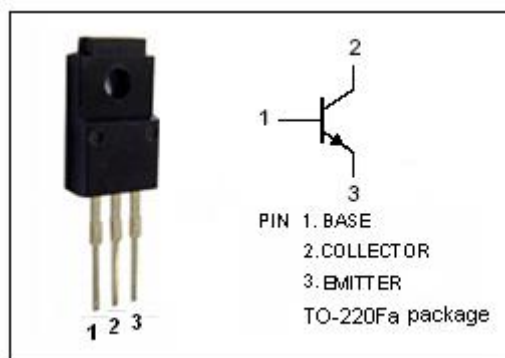
- Mold package that does not require an insulating board or insulation bushing
- High Speed Switching
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

APPLICATIONS

- This transistor is ideal for use in switching power supplies, DC/DC converters, motor drivers, solenoid drivers and other low-voltage power supply devices, as well as for high current switching.

ABSOLUTE MAXIMUM RATINGS (T_a=25°C)

SYMBOL	PARAMETER	VALUE	UNIT
V _{CBO}	Collector-Base Voltage	100	V
V _{CEO}	Collector-Emitter Voltage	100	V
V _{EBO}	Emitter-Base Voltage	7	V
I _C	Collector Current-Continuous	10	A
I _{CM}	Collector Current-Peak	20	A
I _B	Base Current-Continuous	6	A
P _C	Collector Power Dissipation @T _a =25°C	2	W
	Collector Power Dissipation @T _c =25°C	30	
T _j	Junction Temperature	150	°C
T _{stg}	Storage Temperature Range	-55~150	°C



isc Silicon NPN Power Transistor

2SC4336

ELECTRICAL CHARACTERISTICS

T_C=25°C unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT
V _{(BR)CEO}	Collector-Emitter Breakdown Voltage	I _C = 25mA; I _B = 0	100			V
V _{CE(sat)} -1	Collector-Emitter Saturation Voltage	I _C =6A; I _B = 300mA			0.3	V
V _{CE(sat)} -2	Collector-Emitter Saturation Voltage	I _C = 8A; I _B = 400mA			0.5	V
V _{BE(sat)} -1	Base-Emitter Saturation Voltage	I _C =6A; I _B = 300mA			1.2	V
V _{BE(sat)} -2	Base-Emitter Saturation Voltage	I _C = 8A; I _B = 400mA			1.5	V
I _{CBO}	Collector Cutoff Current	V _{CB} =100V; I _E = 0			10	μ A
I _{EBO}	Emitter Cutoff Current	V _{EB} = 5V; I _C = 0			10	μ A
h _{FE-1}	DC Current Gain	I _C = 1A; V _{CE} = 2V	100			
h _{FE-2}	DC Current Gain	I _C =2A; V _{CE} = 2V	100		400	
h _{FE-3}	DC Current Gain	I _C =6A; V _{CE} = 2V	60			
f _T	Current-Gain—Bandwidth Product	I _C = 500mA; V _{CE} = 10V; f= 1MHz		150		MHz

Switching Times

t _{on}	Turn-on Time	I _C =6A; I _{B1} = 0.3A; I _{B2} = -0.3A; V _{CC} = 50V			0.3	μ s
t _s	Storage Time				1.5	μ s
t _f	Fall Time				0.3	μ s

◆ h_{FE-2} Classifications

M	L	K
100-200	150-300	200-400

**NOTICE:**

ISC reserves the rights to make changes of the content herein the datasheet at any time without notification. The information contained herein is presented only as a guide for the applications of our products.

ISC products are intended for usage in general electronic equipment. The products are not designed for use in equipment which require specialized quality and/or reliability, or in equipment which could have applications in hazardous environments, aerospace industry, or medical field. Please contact us if you intend our products to be used in these special applications.

ISC makes no warranty or guarantee regarding the suitability of its products for any particular purpose, nor does ISC assume any liability arising from the application or use of any products, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages.